

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology
- Low threshold voltage
- Exposed drain pad for excellent thermal conduction
- Tin-plated 100% solderable side pads for optical solder inspection
- ElectroStatic Discharge (ESD) protection > 1 kV HBM

3. Applications

- LED driver
- Power management
- Low-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Quie	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	20	V
V _{GS}	gate-source voltage			-12	-	12	V
I _D	drain current	V_{GS} = 4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-	11.4	А
Static characteristics							
R _{DSon}	drain-source on-state resistance	V _{GS} = 4.5 V; I _D = 7.9 A; T _j = 25 °C		-	12	16	mΩ

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².



5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain		D
2	D	drain		
3	G	gate		G (The second s
4	S	source		
5	D	drain	Transparent top view	
6	D	drain	DFN2020MD-6 (SOT1220)	S 017aaa255
7	D	drain		
8	S	source		

6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PMPB12UNE	DFN2020MD-6	DFN2020MD-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1220				

7. Marking

Table 4. Marking codes	
Type number	Marking code
PMPB12UNE	2Y

8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	20	V
V _{GS}	gate-source voltage			-12	12	V
I _D	drain current	V_{GS} = 4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	11.4	А
		V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	7.9	А
		V _{GS} = 4.5 V; T _{amb} = 100 °C	[1]	-	5	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	32	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	470	mW
		T _{amb} = 25 °C; t ≤ 5 s	[1]	-	1.56	W
		T _{sp} = 25 °C		-	12.5	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-dra	in diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	1.5	А

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².
 Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

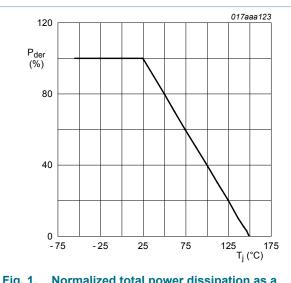
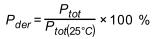
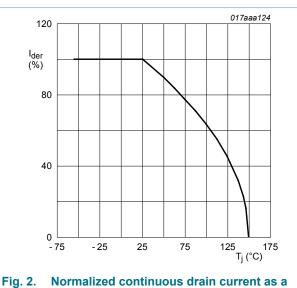
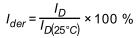


Fig. 1. Normalized total power dissipation as a function of junction temperature



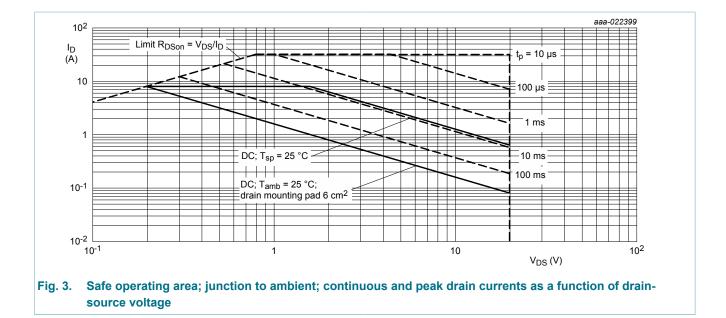


function of junction temperature



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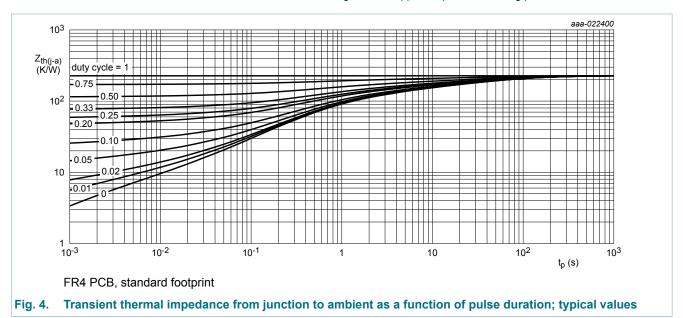
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9. Thermal characteristics

Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	230	265	K/W
			[<u>2]</u>	-	70	80	K/W
		in free air; t ≤ 5 s	[2]	-	34	39	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	5	10	K/W

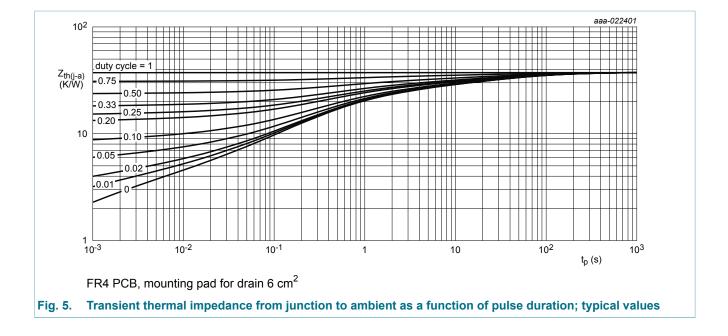
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².



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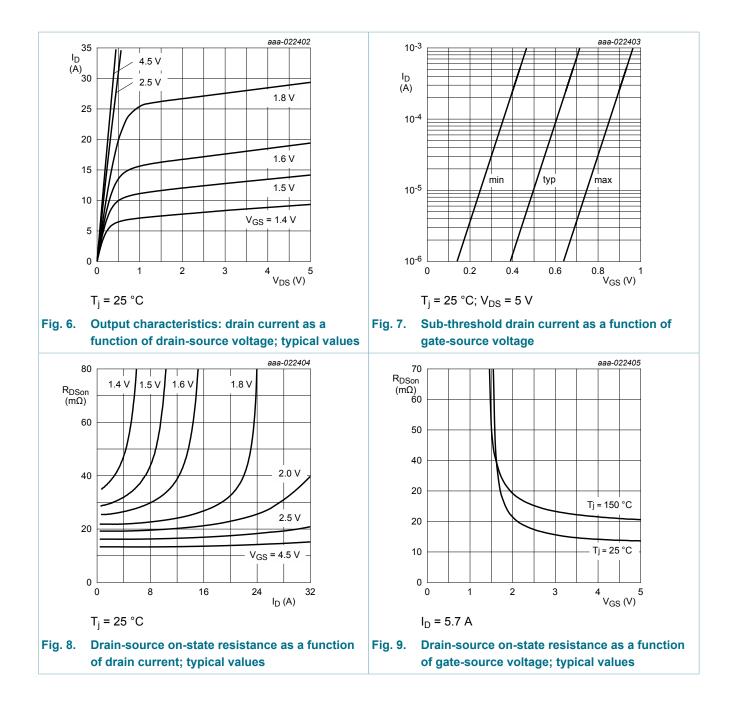


10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	20	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = 250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	0.4	0.65	0.9	V
I _{DSS}	drain leakage current	V_{DS} = 20 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V_{GS} = 8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	10	μA
		V_{GS} = -8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
		V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	1	μA
		V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-1	μA
		V_{GS} = 2.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	100	nA
		V_{GS} = -2.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-100	nA
Doon	drain-source on-state	V_{GS} = 4.5 V; I _D = 7.9 A; T _j = 25 °C	-	12	16	mΩ
	resistance	V _{GS} = 4.5 V; I _D = 7.9 A; T _j = 150 °C	-	19	25	mΩ
		V _{GS} = 2.5 V; I _D = 7.1 A; T _j = 25 °C	-	15	20	mΩ
		V _{GS} = 1.8 V; I _D = 1.9 A; T _j = 25 °C	-	20	29	mΩ
9 _{fs}	forward transconductance	V_{DS} = 10 V; I _D = 7.9 A; T _j = 25 °C	-	18	-	S
R _G	gate resistance	f = 1 MHz	-	1.8	-	Ω
Dynamic ch	aracteristics					
Q _{G(tot)}	total gate charge	V_{DS} = 10 V; I _D = 6 A; V _{GS} = 4.5 V;	-	10.9	17	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1.3	-	nC
Q _{GD}	gate-drain charge		-	2.1	-	nC
C _{iss}	input capacitance	V_{DS} = 10 V; f = 1 MHz; V_{GS} = 0 V;	-	1220	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	124	-	pF
C _{rss}	reverse transfer capacitance		-	102	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 10 V; I _D = 6 A; V _{GS} = 4.5 V;	-	10	-	ns
t _r	rise time	R _{G(ext)} = 6 Ω; T _j = 25 °C	-	24	-	ns
t _{d(off)}	turn-off delay time		-	32	-	ns
t _f	fall time		-	34	-	ns
Source-drai	n diode		I			
V _{SD}	source-drain voltage	I _S = 1.5 A; V _{GS} = 0 V; T _i = 25 °C	-	0.7	1.2	V

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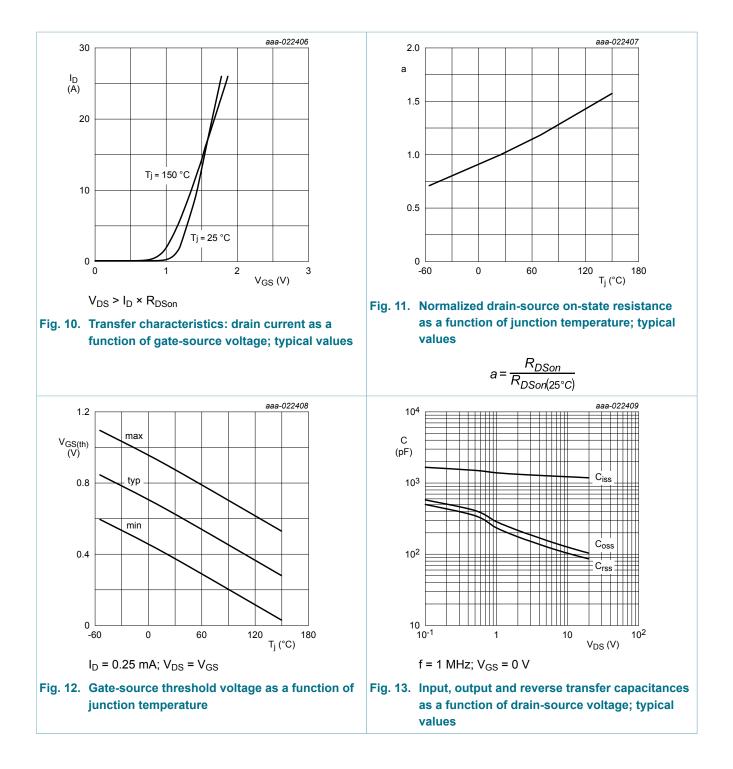
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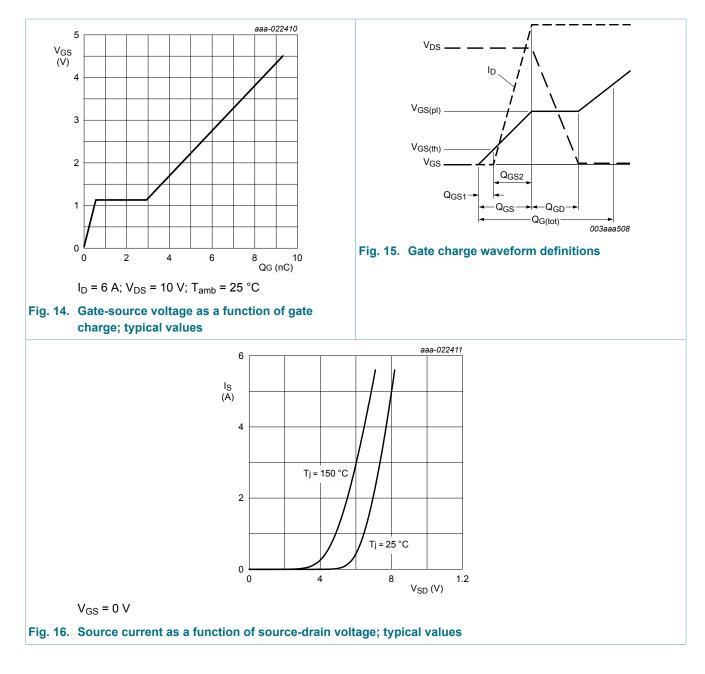
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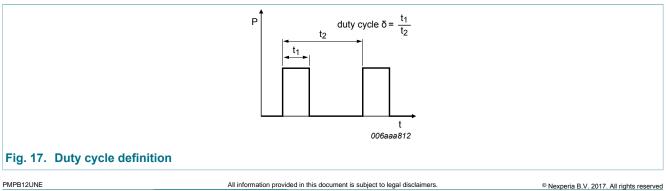
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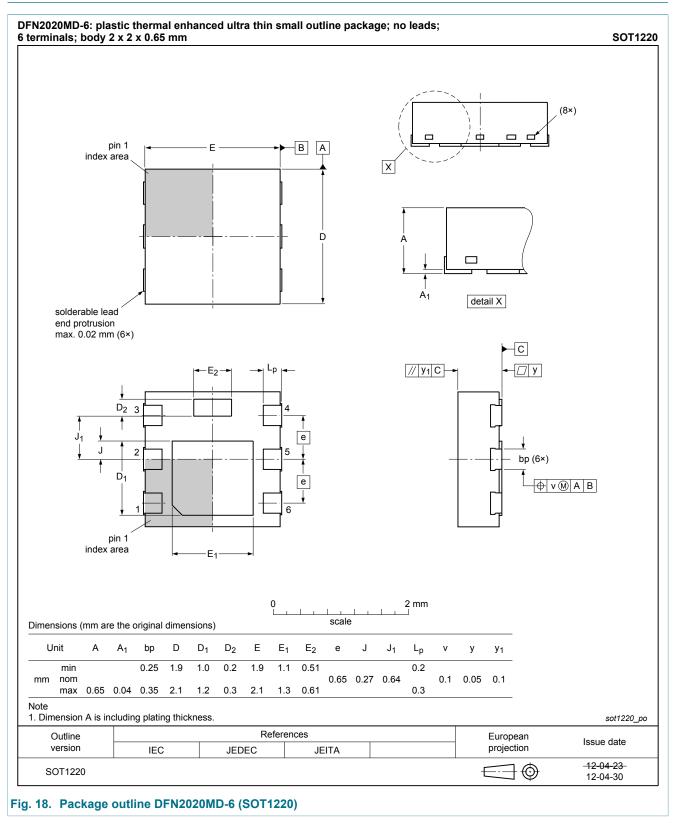


11. Test information



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12. Package outline

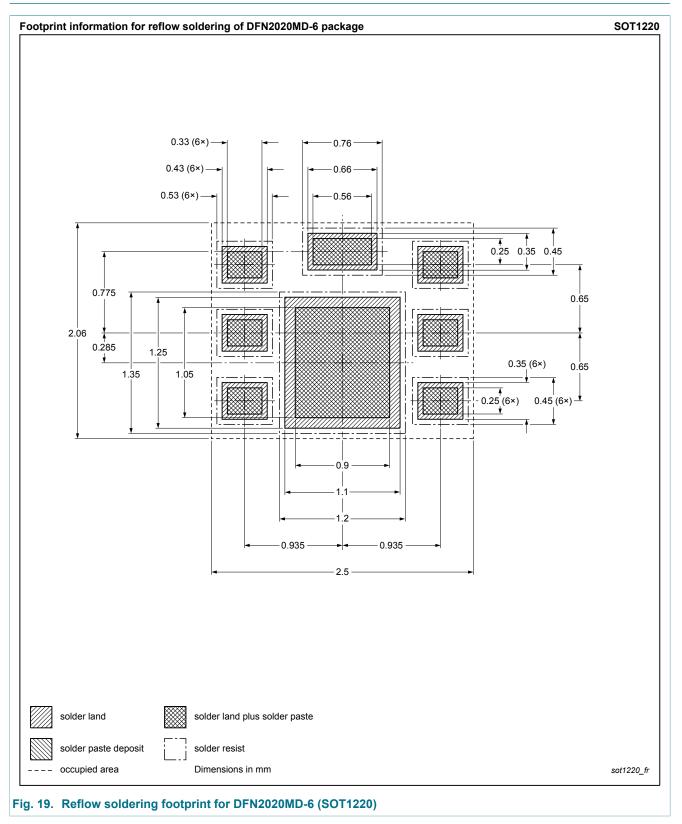


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13. Soldering



14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PMPB12UNE v.1	20160412	Product data sheet	-	-			

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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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